

SLD1134VL

650nm Pulsation Red Laser Diode

Description

The SLD1134VL is a pulsation red laser diode designed for DVD systems.

Features

- Low noise
- Standard package (\$5.6mm)

Application

DVD

Structure

- AlGaInP quantum well-structure laser diode
- PIN photo diode for optical power output monitor

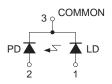
Recommended Optical Power Output

4mW

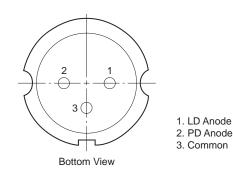
Absolute Maximum Ratings (Tc = 25°C)

 Optical power output 	Po		5	mW
 Reverse voltage 	Vr	LD	2	V
		PD	20	V
Operating temperature	Topr		-10 to +70	°C
 Storage temperature 	Tstg		-40 to +85	°C

Connection Diagram

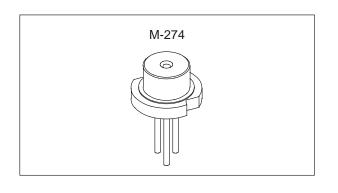


Pin Configuration



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	ltem	Symbol	Conditions	Min.	Тур.	Max.	Unit
Threshold	current	lth			65	80	mA
Operating current		lop1	Po = 4mW		75	90	mA
		lop2 *1				120	mA
Operating	voltage	Vop	Po = 4mW		2.3	2.8	V
Wavelengt	h	λρ	Po = 4mW	640	655	660	nm
Angle	Perpendicular	θ⊥	- Po = 4mW	25	35	40	degree
	Parallel	θ//		7	8.5	12	degree
Positional	Position	ΔΧ, ΔΥ, ΔΖ	Po = 4mW			±80	μm
	Angle –	Δφ//				±2	degree
		$\Delta \phi \perp$				±3	degree
Differential	efficiency	ησ	Po = 4mW	0.15	0.4	0.7	mW/mA
Astigmatis	m	As	Po = 4mW		10		μm
Monitor cu	rrent	Imon	Po = 4mW VR = 5V	0.05	0.1	0.25	mA

Electrical and Optical Characteristics

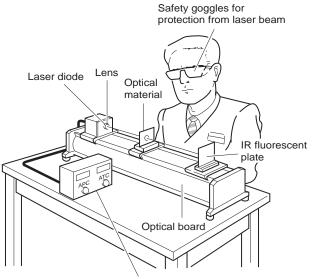
Tc: Case temperature

*1 Tc = 70°C

Handling Precautions

(1) Eye protection against laser beams

The optical output of laser diodes ranges from several mW to 4W. However the optical power density of the laser beam at the diode chip reaches 1MW/cm². Unlike gas lasers, since laser diode beams are divergent, uncollimated laser diode beams are fairly safe at a laser diode. For observing laser beams, ALWAYS use safety goggles that block infrared rays. Usage of IR scopes, IR cameras and fluorescent plates is also recommended for monitoring laser beams safely.

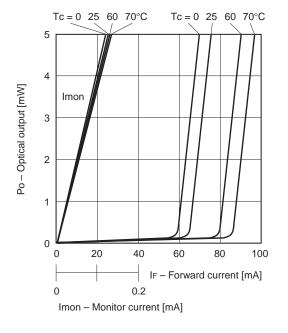


Optical power output control device Temperature control device

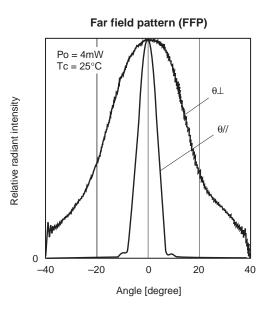
(2) Prevention of surge current and electrostatic discharge

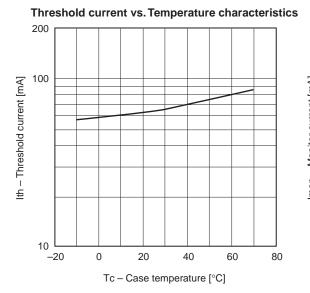
Laser diode is most sensitive to electrostatic discharge among semiconductors. When a large current is passed through the laser diode even for an extremely short time (in the order of nanosecond), the strong light emitted from the laser diode promotes deterioration and then laser diodes are destroyed. Therefore, note that the surge current should not flow the laser diode driving circuit from switches and others. Also, if the laser diode is handled carelessly, it may be destructed instantly because electrostatic discharge is easily applied by a human body. Be great careful about excess current and electrostatic discharge.

Example of Representative Characteristics

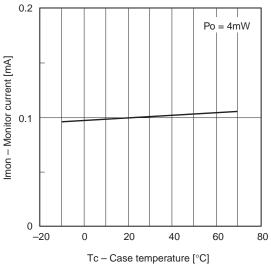


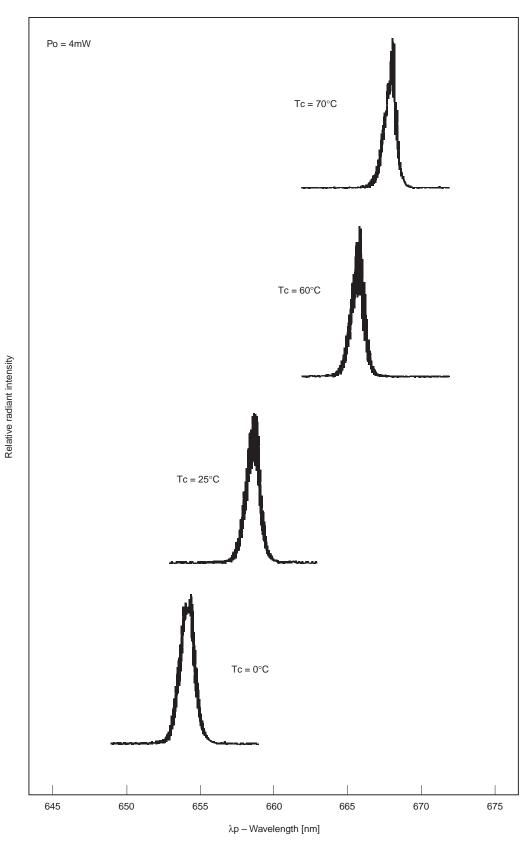
Optical power output vs. Forward current characteristics Optical power output vs. Monitor current characteristics





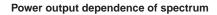
Monitor current vs. Temperature characteristics

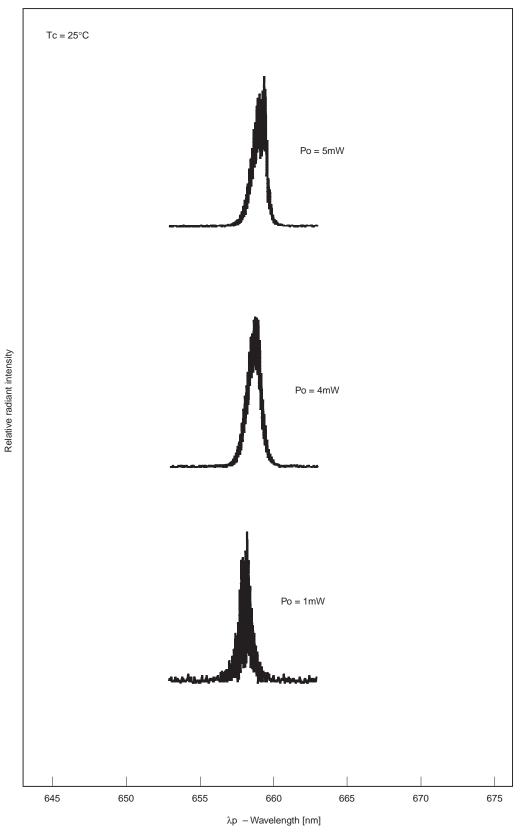




Temperature dependence of spectrum

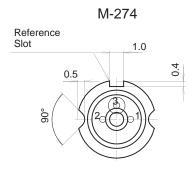
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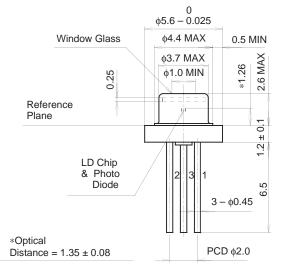




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Package Outline Unit: mm





SONY CODE	M-274	PACKAGE WEIGHT	0.3g	
EIAJ CODE				
JEDEC CODE				